Mott-Hubbard Metal-Insulator Transition in Paramagnetic V$_2$O$_3$: An LDA+DMFT(QMC) Study

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The electronic properties of paramagnetic V$_2$O$_3$ are investigated by the computational scheme LDA+DMFT(QMC). This approach merges the local density approximation (LDA) with dynamical mean-field theory (DMFT) and uses quantum Monte Carlo simulations (QMC) to solve the effective Anderson impurity model of DMFT. Starting with the crystal structure of metallic V$_2$O$_3$ and insulating (V$_{0.96}$Cr$_{0.038}$)$_2$O$_3$ we find a Mott-Hubbard transition at a Coulomb interaction $U \approx 5$ eV. The calculated spectrum is in very good agreement with experiment. Furthermore, the orbital occupation and the spin state $S = 1$ determined by us agree with recent polarization dependent x-ray-absorption experiments.

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The metal-insulator transition within the paramagnetic phase of V$_2$O$_3$ is generally considered to be the classical example of a Mott-Hubbard metal-insulator transition (MIT) [1]. During the last few years, our understanding of the MIT in the one-band Hubbard model has considerably improved, in particular due to the application of dynamical mean-field theory (DMFT).

Within DMFT the electronic lattice problem is mapped onto a self-consistent single-impurity Anderson model. The mapping becomes exact in the limit of infinite coordination number [2] and allows one to investigate the dynamics of correlated lattice electrons nonperturbatively at all interaction strengths. This is of essential importance for a problem such as the MIT which occurs at a Coulomb interaction comparable to the electronic bandwidth. The transition is signaled by the collapse of the quasiparticle peak at the Fermi energy when the interaction is increased [3]. Rozenberg et al. [4] first applied DMFT to investigate the metal-insulator transition in V$_2$O$_3$ in terms of the one-band Hubbard model. Subsequently, the influence of orbital degeneracy was studied by means of the two- [5–7] and three-band [6] Hubbard model for the semieliptic density of states (DOS) of a Bethe lattice.

Clearly, a realistic theory of V$_2$O$_3$ must take into account the complicated electronic structure of this system. In the high-temperature paramagnetic phase V$_2$O$_3$ has a corundum crystal structure in which the V ions are surrounded by an octahedron of oxygen ions. This leads to an electronic structure with a $3d^2V^{5+}$ state, where the two $e_g$ orbitals are empty and the three $t_{2g}$ orbitals are filled with two electrons. A small trigonal distortion lifts the triple degeneracy of the $t_{2g}$ orbitals, resulting in one nondegenerate $a_{1g}$ orbital oriented along the $c$ axis and two degenerate $e_g$ orbitals oriented predominantly in the hexagonal plane. Starting from this orbital structure Castellani et al. [8] proposed a widely accepted model with a strong covalent $a_{1g}$ bond between two V ions along the $c$ axis. This bonding state is occupied by a singlet pair (one electron per V) and hence does not contribute to the local magnetic moment. The remaining electron per V has a twofold orbital degeneracy within the $e_g^p$ orbitals and a spin $S = 1/2$. This $S = 1/2$ model suggested that the half-filled, one-band Hubbard model was the simplest possible electronic model describing V$_2$O$_3$. However, recent experimental results by Park et al. [9] obtained by polarized x-ray spectroscopy seem to require an interpretation in terms of a $S = 1$ spin state, and an $e_g^p$ orbital state with an admixture of $e_g^p a_{1g}$ configurations. Subsequently, Ezhev et al. [10] and Mila et al. [11] argued for $S = 1$ models without and with orbital degeneracy, respectively, for the antiferromagnetic insulating phase of V$_2$O$_3$. LDA+$U$ calculations indicate that the atomic Hund’s rule is responsible for the high-spin ground state of the V ions [10]. While LDA+$U$ may be used to describe the antiferromagnetic insulating phase of V$_2$O$_3$, the metal-insulator transition within the correlated paramagnetic phase is beyond the scope of this approach since the Coulomb interaction is treated within Hartree-Fock. Here the computational scheme LDA+DMFT [12–15], obtained by combining electronic band structure theory (LDA) with the many-body technique DFMT [2], is the best available method for the investigation of real systems close to a Mott-Hubbard MIT [16]. To solve the DMFT equations we employ quantum Monte Carlo simulations (QMC) which yield a numerically exact solution [17]; the resulting calculational scheme is referred to as LDA+DMFT(QMC) [13,15,16].

We start by calculating the density of states (DOS) of paramagnetic metallic V$_2$O$_3$ and paramagnetic insulating (V$_{0.96}$Cr$_{0.038}$)$_2$O$_3$, respectively, within LDA using the crystal structure data of Dernier [18,19]. In the LDA DOS, Fig. 1, one observes the expected behavior: the V $t_{2g}$ states are near the Fermi energy and are split into a nondegenerate $a_{1g}$ band and doubly degenerate $e_g^p$ bands; the V $e_g^p$ states are at higher energies. The results for corundum V$_2$O$_3$ and (V$_{0.96}$Cr$_{0.038}$)$_2$O$_3$ are very similar, and are close to those found by Mattheiss [20] and Ezhev et al. [10] for the corundum and the monoclinic phase.
structure, expressed by a one-particle Hamiltonian $H$ caused by the electronic correlations. We will now show explicitly that the insulating gap is indeed the Coulomb repulsion $U$.

Going from metallic $V_2O_3$ to insulating $(V_{0.96}Cr_{0.038})_2O_3$ the metal-metal distances are increased, in particular, in the crystallographic $c$ direction. This results in a slight narrowing of the $t_{2g}$ and $e_g^*$ bands by about 0.2 and 0.1 eV, respectively, as well as a weak down-shift of the centers of gravity of both groups of bands. Most important is the fact that the insulating gap observed experimentally for the Cr-doped system is missing in the LDA DOS. It is generally believed that this insulating gap is due to strong Coulomb interactions which cannot be described adequately within LDA. Using LDA+DMFT(QMC) we will now show explicitly that the insulating gap is indeed caused by the electronic correlations.

In the LDA+DMFT approach [12–16] the LDA band structure, expressed by a one-particle Hamiltonian $H_{\text{LDA}}^0$, is supplemented with the local Coulomb repulsion $U$ and Hund’s rule exchange $J$:

$$
\hat{H} = \hat{H}_{\text{LDA}}^0 + U \sum_{im} \hat{n}_m \hat{n}_m + \sum_{im\neq nm, \sigma} (V - \delta_{\sigma\bar{\sigma}} J) \hat{n}_m^{\sigma} \hat{n}_n^{\bar{\sigma}} .
$$

Here, $i$ denotes the lattice site; $m$ and $n$ enumerate the three interacting $t_{2g}$ orbitals. The interaction parameters are related by $V = U - 2J$ which holds exactly for degenerate orbitals and is a good approximation for the $t_{2g}$ orbitals which are almost degenerate. Furthermore, since the $t_{2g}$ bands at the Fermi energy are rather well separated from all other bands we restrict the calculation to these bands (for details of the computational scheme, see Refs. [15,16]). With this restriction and by taking into account the lattice symmetry which leads to vanishing off-diagonal matrix elements between the $t_{2g}$ orbitals, one can show that only the LDA DOS of the three $t_{2g}$ bands shown in Fig. 1 enter the LDA+DMFT calculation [16]. While the Hund’s rule coupling $J$ is insensitive to screening effects and may thus be obtained within LDA to a good accuracy ($J = 0.93$ eV [21]), the LDA-calculated value of the Coulomb repulsion $U$ has a typical uncertainty of at least 0.5 eV [15]. For this reason, we adjust $U$ to yield a metal-insulator transition with Cr doping. A posteriori, we compare whether the adjusted value is in the range of what is to be expected from a constraint LDA calculation and whether other experimental properties such as the photoemission spectrum are in agreement with our calculation.

The spectra obtained by LDA+DMFT(QMC) are shown in Fig. 2 [22]. They imply that the critical value of $U$ for the MIT is about 5 eV. Indeed, at $U = 4.5$ eV one observes pronounced quasiparticle peaks at the Fermi energy, i.e., characteristic metallic behavior, even for the crystal structure of $(V_{0.96}Cr_{0.038})_2O_3$, while at $U = 5.5$ eV the form of the calculated spectral function is typical for an insulator for both sets of crystal structure parameters. At $U = 5.0$ eV one is then at, or very close to, the MIT since there is a pronounced dip in the DOS at the Fermi energy for both $a_{1g}$ and $e_g^*$ orbitals for the crystal structure of $(V_{0.96}Cr_{0.038})_2O_3$, while for pure $V_2O_3$ one still finds quasiparticle peaks. (We note that at $T = 0.1$ eV one observes only metallic-like and insulator-like behavior, with a rapid but smooth crossover between these two phases, since a sharp MIT occurs only at lower temperatures [3,5]). The critical value of the Coulomb interaction $U = 5$ eV is in reasonable agreement with the values determined spectroscopically by fitting to model calculations, and by constrained LDA. The former gives $U = 4$–5 eV for vanadium oxides [23] while the latter yields $U = 3$ eV (for LaVO$_3$) to $U = 8$ eV, depending on whether the $e_g$ electrons participate in the screening or not; without screening, one finds $U = 6$–7 eV [24].

![FIG. 1. Partial DOS of the 3d bands for paramagnetic metallic $V_2O_3$ and insulating $(V_{0.96}Cr_{0.038})_2O_3$.](image)

![FIG. 2. LDA+DMFT(QMC) spectra for paramagnetic $(V_{0.96}Cr_{0.038})_2O_3$ (“iso.”) and $V_2O_3$ (“met.”) at $U = 4.5$, 5, and 5.5 eV, and $T = 0.1$ eV $\approx 1000$ K.](image)
To compare with the photoemission spectrum of $\text{V}_2\text{O}_3$ by Schramme et al. [25], the LDA+DMFT(QMC) spectra of Fig. 2 are multiplied with the Fermi function at $T = 0.1$ eV and Gauss broadened by 0.05 eV to account for the experimental resolution. The theoretical results for $U = 5$ eV are seen to be in good agreement with experiment (Fig. 3), in contrast with the LDA results. We also note that the DOS is highly asymmetric with respect to the Fermi energy due to the orbital degrees of freedom. The comparison between our results, the data of Müller et al. [26] obtained by x-ray absorption measurements, and LDA in Fig. 4 shows that, in contrast with LDA, our results not only describe the different bandwidths above and below the Fermi energy ($= \text{6 eV and } \approx 2-3 \text{ eV}$, respectively) correctly, but even resolve the two-peak structure above the Fermi energy. Also the interpretation of the two peaks is different in LDA and LDA+DMFT(QMC). While in the latter approach the peak at lower energies (1 eV) has predominantly $a_{1g}$ character and the peak at higher energy (3 eV) is due to the $e_g$ Hubbard bands (see Fig. 2), in LDA the $a_{1g}$ and $e_g$ states contribute only below 1.8 eV such that the second peak is entirely due to the $e_g^\pi$ states (see Fig. 1).

Particularly interesting are the spin and the orbital degrees of freedom in $\text{V}_2\text{O}_3$. We find (not shown) that for $U \geq 3$ eV the squared local magnetic moment $\langle m_z^2 \rangle = \langle \sum_n (\hat{n}_{nm} - \hat{n}_{mn}) \rangle^2$ saturates at a value of 4, i.e., there are two electrons with the same spin direction in the $(a_{1g}, e_g^\pi, e_g^\sigma)$ orbitals. Thus, we conclude that the spin state of $\text{V}_2\text{O}_3$ is $S = 1$ throughout the Mott-Hubbard transition region. Note, that at $U = J = 0$ only the lower maximum of the $a_{1g}$ band is filled with both spin species (Fig. 1). This $a_{1g}$ singlet corresponds to the filled $a_{1g}$ binding orbital in the Castellani et al. $S = 1/2$ model. However, it is destroyed with increasing $U$ and $J$ as the system tries to avoid double occupations and unaligned spins, respectively. Our $S = 1$ result agrees with the measurements of Park et al. [9] and also with the data for the high-temperature susceptibility [27]. The latter correspond to an effective magnetic moment $\mu_{\text{eff}} = 2.66 \mu_B$ which is close to the ideal value $\mu_{\text{eff}} = 2.83 \mu_B$ for $S = 1$. The result is at odds with a $S = 1/2$ model and with the results for a one-band Hubbard model where $m_2^e$ changes substantially at the MIT [3].

For the orbital degrees of freedom we find a predominant occupation of the $e_g^\pi$ orbitals, but with a significant admixture of $a_{1g}$ orbitals. This admixture decreases at the MIT: in the metallic phase we determine the occupation of the $(a_{1g}, e_g^\pi, e_g^\sigma)$ orbitals as $(0.37, 0.815, 0.815)$, and in the insulating phase as $(0.28, 0.86, 0.86)$. This should be compared with the experimental results of Park et al. [9]. From their analysis of the linear dichroism data the authors concluded that the ratio of the configurations $e_g^\pi e_g^\sigma e_g^\pi a_{1g}$ is equal to 1:1 for the paramagnetic metallic and 3:2 for the paramagnetic insulating phase, corresponding to a one-electron occupation of $(0.5, 0.75, 0.75)$ and $(0.4, 0.8, 0.8)$, respectively. Although our results show a somewhat smaller value for the admixture of $a_{1g}$ orbitals, the overall behavior, including the tendency of a decrease of the $a_{1g}$ admixture across the transition to the insulating state, are well reproduced. This agrees with the LDA+$U$ calculation for the antiferromagnetic insulating phase [10]. Further experimental evidence for predominant $(e_g^\pi, e_g^\sigma)$ configurations was obtained by polarized neutron diffraction by Brown et al. [28]. Measuring the spatial distribution of the magnetization induced by a magnetic field, they showed that the moment induced on the V atoms is almost entirely due to the electrons in the $e_g^\pi$ orbitals. Note that this orbital occupation and the spectral distribution of Fig. 2 are due to DOS effects, i.e., differences in the centers of gravity and bandwidths of the $e_g^\pi$ orbitals. The authors concluded that the ratio of the configurations $e_g^\pi e_g^\sigma e_g^\pi a_{1g}$ is equal to 1:1 for the paramagnetic metallic and 3:2 for the paramagnetic insulating phase, corresponding to a one-electron occupation of $(0.5, 0.75, 0.75)$ and $(0.4, 0.8, 0.8)$, respectively. Although our results show a somewhat smaller value for the admixture of $a_{1g}$ orbitals, the overall behavior, including the tendency of a decrease of the $a_{1g}$ admixture across the transition to the insulating state, are well reproduced. This agrees with the LDA+$U$ calculation for the antiferromagnetic insulating phase [10]. Further experimental evidence for predominant $(e_g^\pi, e_g^\sigma)$ configurations was obtained by polarized neutron diffraction by Brown et al. [28]. Measuring the spatial distribution of the magnetization induced by a magnetic field, they showed that the moment induced on the V atoms is almost entirely due to the electrons in the $e_g^\pi$ orbitals. Note that this orbital occupation and the spectral distribution of Fig. 2 are due to DOS effects, i.e., differences in the centers of gravity and bandwidths of the $e_g^\pi$ orbitals.

![FIG. 3.](image1)  
(a) LDA+DMFT(QMC) spectrum for $U = 4.5$, 5, and 5.5 eV at $T = 0.1$ eV = 1000 K; (b) comparison with the LDA spectrum and the photoemission experiment by Schramme et al. [25] for two different $\text{V}_2\text{O}_3$ single-crystal surfaces at $T = 300$ K. Note that the (1012) surface has the same coordination number as the bulk.

![FIG. 4.](image2)  
Comparison of the LDA and LDA+DMFT(QMC) spectra at $T = 0.1$ eV (Gaussian broadened with 0.2 eV) with the x-ray absorption data of Müller et al. [26]. The LDA and QMC curves are normalized differently since the $e_g^\pi$ states, which are shifted towards higher energies if the Coulomb interaction is included, are neglected in our calculation.
and $a_{1g}$ bands as well as the band-edge maxima of the $a_{1g}$ band (Fig. 1). The latter are due to a bonding-antibonding splitting.

In conclusion, starting from the LDA-calculated spectra for paramagnetic $V_2O_3$ and $(V_{0.962}Cr_{0.038})_2O_3$, and including the missing electronic correlations via DMFT(QMC), we showed that a Mott-Hubbard MIT occurs in the paramagnetic phase at $U \approx 5$ eV. Our results are in very good agreement with the experimentally determined photoemission and x-ray absorption spectra, i.e., above and below the Fermi energy. Furthermore, we calculate the spin state to be $S = 1$ and find an orbital admixture of $e_g^\pi e_g^\sigma$ and $e_g^\sigma a_{1g}$ configurations, which both agree with recent experiments. Thus LDA+DMFT(QMC) provides a remarkably accurate microscopic theory of the strongly correlated electrons in the paramagnetic phase of $V_2O_3$.

The MIT will eventually become first order at lower temperatures [3,4]; QMC simulations at $T = 300$ K are under way, but are very computer expensive. Furthermore, future investigations will have to clarify the origin of the discontinuous lattice distortion at the first-order MIT which leaves the lattice symmetry unchanged. Here various scenarios are possible [29,30]. In particular, the MIT might be the driving force behind the lattice distortion by causing a thermodynamic instability with respect to changes of the lattice volume and distortions.

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[16] For an introduction into LDA+DMFT, see K. Held et al., cond-mat/0010395.

[17] For a comparison of LDA+DMFT results for the photoemission spectra of La$_{1-x}$Sr$_x$TiO$_3$ obtained by different numerical techniques, see Ref. [15].


[19] Use of the crystal structure of Cr-doped $V_2O_3$ for the insulating phase of pure $V_2O_3$ is justified by the observation that Cr doping is equivalent to the application of (negative) pressure.


[22] All QMC results presented were obtained for $T = 0.1$ eV. Simulations for $V_2O_3$ at $U = 5$ eV, $T = 0.143$ eV, and $T = 0.067$ eV suggest, however, only a minor smoothing of the spectrum with increasing temperature.


